

Symbol	Parameter	Ratings	Units	
V _{DSS}	Drain to Source Voltage		150	V
V _{GS}	Gate to Source Voltage		±20	V
I _D	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	35	•
	Pulsed Drain Current	T _C = 25°C	See Figure4	Α
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	78	mJ
-	Power Dissipation		150	W
P _D	Derate above 25°C		1.0	W/ºC
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C
$R_{\theta JC}$	Thermal Resistance Junction to Case		1.0	°C/W
$R_{\theta JA}$	Maximum Thermal Resistance Junction to Ambient	(Note 3)	43	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDB42AN15A0	FDB42AN15A0-F085	D2-PAK(TO-263)	330mm	24mm	800 units

Notes:

1: Current is limited by bondwire configuration.

2: Starting T_J = 25°C, L = 0.2mH, I_{AS} = 28A, V_{DD} = 100V during inductor charging and V_{DD} = 0V during time in avalanche 3: $R_{\theta,JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta,JC}$ is guaranteed by design while $R_{\theta,JA}$ is determined by the user's board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

Off Cha		Test Conditions		Min	Тур	Max	Units
	racteristics						
B _{VDSS}	Drain to Source Breakdown Voltage	I _D = 250μA, V ₀	_{GS} = 0V	150	-	-	V
I _{DSS}	Drain to Source Leakage Current	V _{DS} =150V, V _{GS} = 0V	$T_{J} = 25^{\circ}C$ $T_{J} = 175^{\circ}C(Note 4)$	-	-	1 1	μA mA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20V$	<u> </u>	-	-	±100	nA
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D$		2.0	3.0 36	4.0 42	V
Vaanus	Gate to Source Threshold Voltage	$V_{ab} = V_{ab}$	= 2504	2.0	3.0	4.0	V
r _{DS(on)}	Drain to Source On Resistance	I _D = 12A, V _{GS} = 10V	$T_{J} = 25^{\circ}C$ $T_{J} = 175^{\circ}C(Note 4)$	-	36 89	42	mΩ mΩ
	c Characteristics						
	c Characteristics						
Dynami	c Characteristics	V - 25V/V	- 0)/	-	2040	-	pF
Dynami C _{iss}		V _{DS} = 25V, V _C f = 1MHz	_{-S} = 0V,	-	2040 216	-	pF pF
Dynami C _{iss} C _{oss}	Input Capacitance		_S = 0V,	-			
Dynami C _{iss} C _{oss} C _{rss}	Input Capacitance Output Capacitance			- - -	216		pF
Dynami C _{iss} C _{oss} C _{rss} R _g	Input Capacitance Output Capacitance Reverse Transfer Capacitance	$f = 1MHz$ $f = 1MHz$ $V_{GS} = 0 \text{ to } 10^{10}$	-	-	216 48		pF pF
Dynami C _{iss} C _{oss} C _{rss} R _g Q _{g(ToT)}	Input Capacitance Output Capacitance Reverse Transfer Capacitance Gate Resistance	f = 1MHz f = 1MHz	-		216 48 1		pF pF Ω
	Input Capacitance Output Capacitance Reverse Transfer Capacitance Gate Resistance Total Gate Charge at 10V	$f = 1MHz$ $f = 1MHz$ $V_{GS} = 0 \text{ to } 10^{10}$	/V _{DD} = 75V	- - -	216 48 1 30	- - - 36	pF pF Ω nC

Drain-Source Diode Characteristics

Fall Time

Turn-Off Time

V_{SD}	Source to Drain Diode Voltage	I _{SD} = 12A, V _{GS} = 0V	-	-	1.25	V
		I _{SD} = 6A, V _{GS} = 0V	-	-	1.2	V
T _{rr}	Reverse Recovery Time	I _F = 12A, dI _{SD} /dt = 100A/μs,	-	67	72	ns
Q _{rr}	Reverse Recovery Charge	V _{DD} =120V	-	193	222	nC

3

-

-

29

ns

ns

-

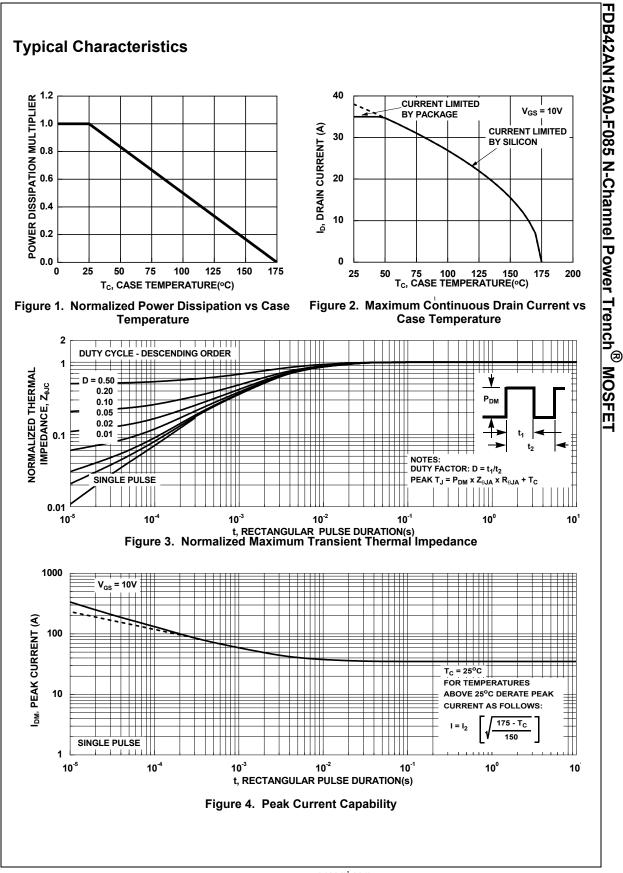
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Notes:

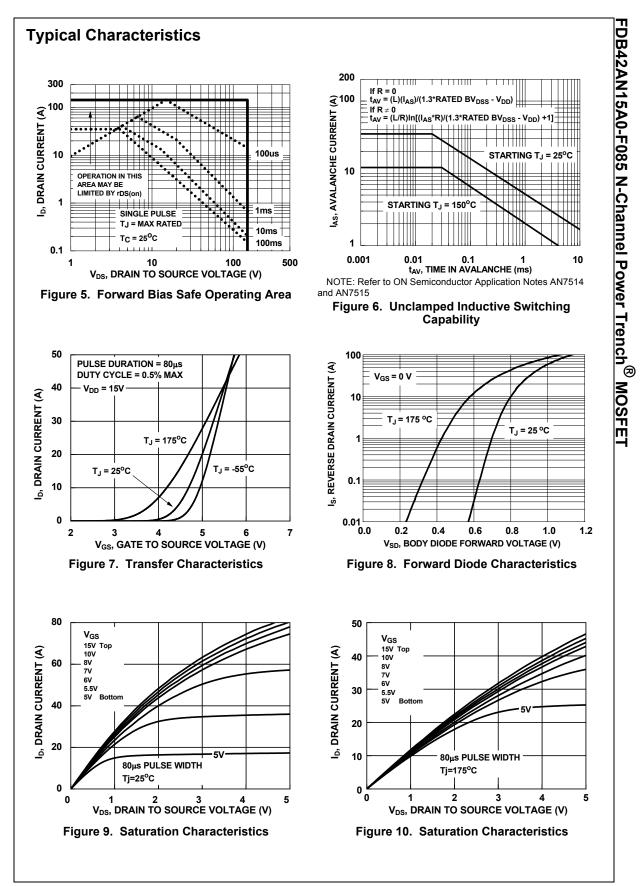
t_f

t_{off}

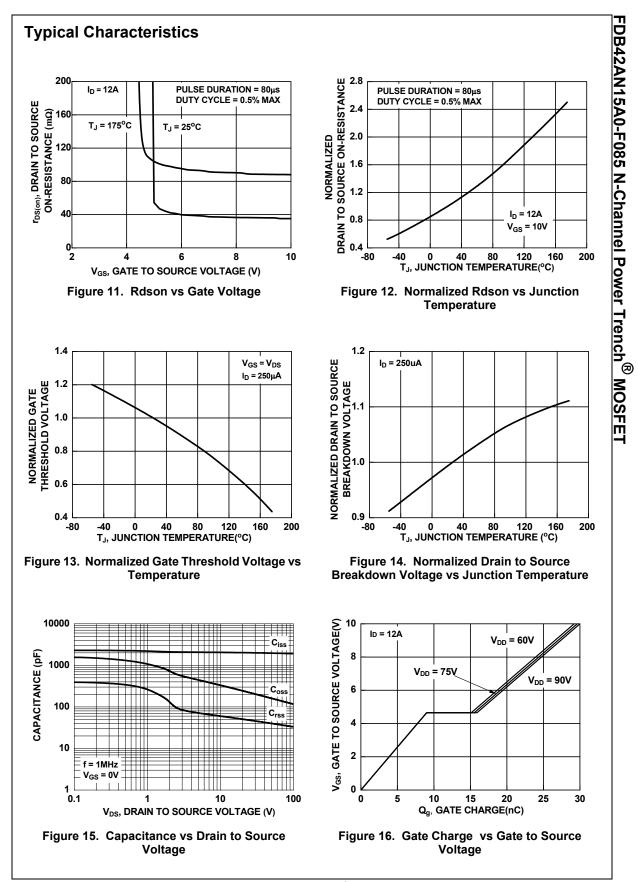
4: The maximum value is specified by design at T_J = 175°C. Product is not tested to this condition in production.



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